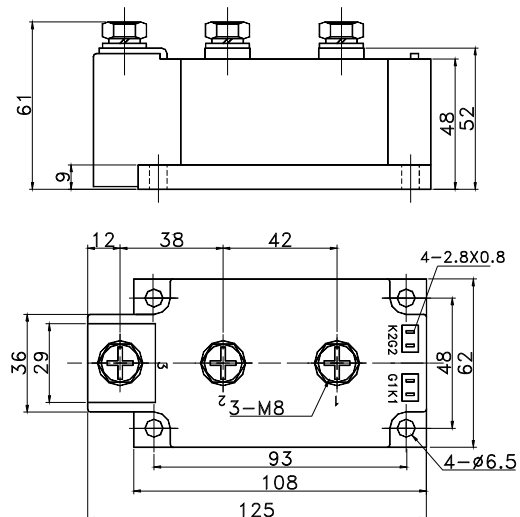
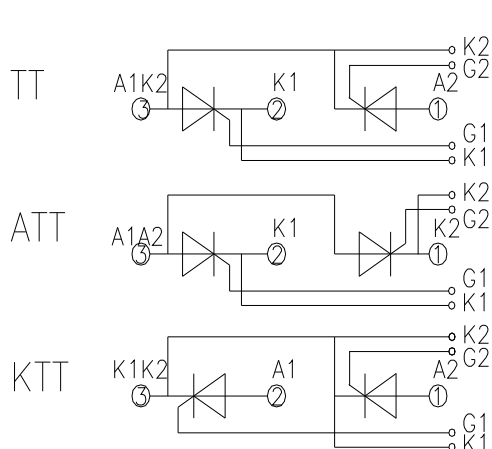


TT300 ATT300 KTT300

SYMBOL	CHARACTERISTIC	TEST CONDITIONS	T _j (°C)	VALUE			UNIT
				Min	Type	Max	
I _{T(AV)}	Mean on-state current	180° half sine wave 50Hz Single side cooled, T _c =85°C	125			300	A
I _{T(RMS)}	RMS on-state current	Single side cooled, T _c =85°C	125			471	A
V _{DRM} V _{RRM}	Repetitive peak off-state voltage Repetitive peak reverse voltage	V _{DRM} &V _{RRM} tp=10ms V _{DSM} &V _{RSM} = V _{DRM} &V _{RRM} +200V respectively	125	600		1800	V
I _{DRM} I _{RRM}	Repetitive peak current	at V _{DRM} at V _{RRM}	125			40	mA
I _{TSM}	Surge on-state current	10ms half sine wave	125			9.30	KA
I ² t	I ² T for fusing coordination	V _R =60%V _{RRM}				441	A ² s*10 ³
V _{TO}	Threshold voltage		125			0.80	V
r _T	On-state slop resistance					0.72	mΩ
V _{TM}	Peak on-state voltage	I _{TM} =900A	125			1.58	V
dv/dt	Critical rate of rise of off-state voltage	V _{DM} =67%V _{DRM}	125			800	V/μs
di/dt	Critical rate of rise of on-state current	From 67%V _{DRM} to 900A, Gate source 1.5A t _r ≤0.5μs Repetitive	125			100	A/μs
I _{GT}	Gate trigger current	V _A =12V, I _A =1A	25	30		180	mA
V _{GT}	Gate trigger voltage			1.0		2.5	V
I _H	Holding current			20		100	mA
V _{GD}	Non-trigger gate voltage	At 67%V _{DRM}	125			0.2	V
R _{th(j-c)}	Thermal resistance Junction to heatsink	At 180° sine Single side cooled				0.100	°C /W
V _{iso}	Isolation voltage	50Hz, R.M.S, t=1min, I _{iso} :1mA(MAX)		2500			V
F _m	Thermal connection torque(M8)				0.45		N·m
	Mounting torque(M6)				0.30		N·m
T _{stg}	Stored temperature			-40		140	°C
W _t	Weight				1340		g
Outline	402F3						

OUTLINE DRAWING & CIRCUIT DIAGRAM



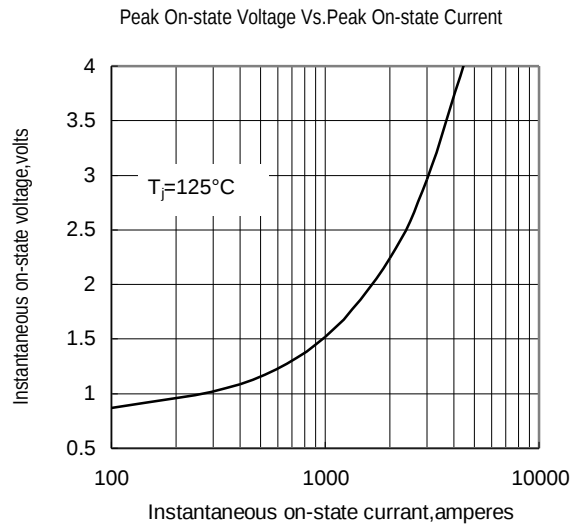


Fig.1

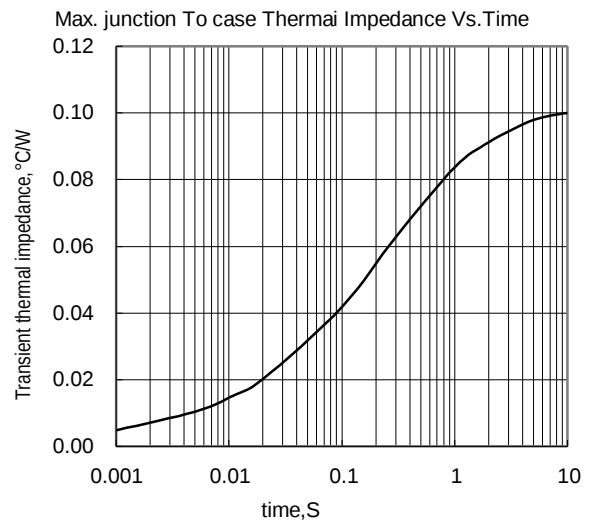


Fig.2

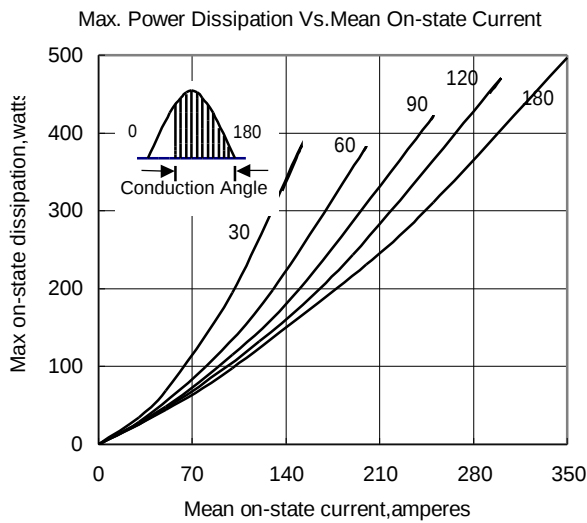


Fig.3

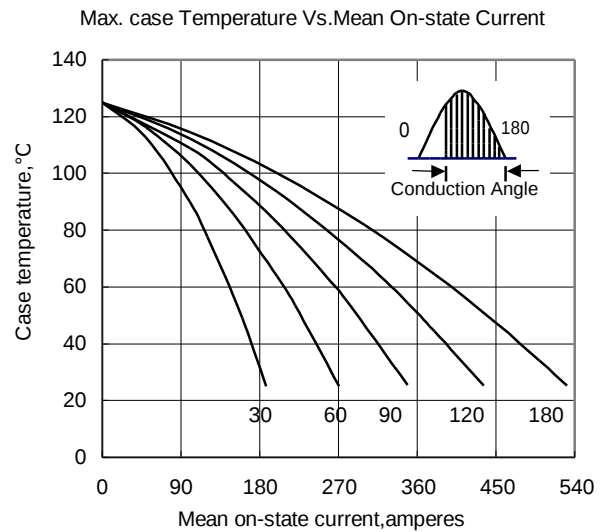


Fig.4

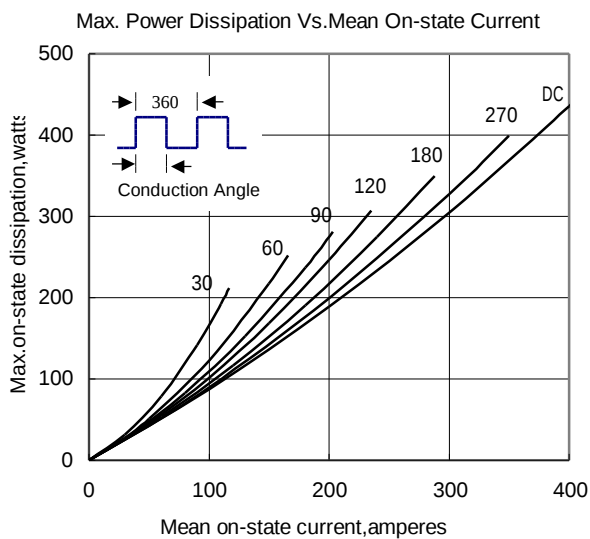


Fig.5

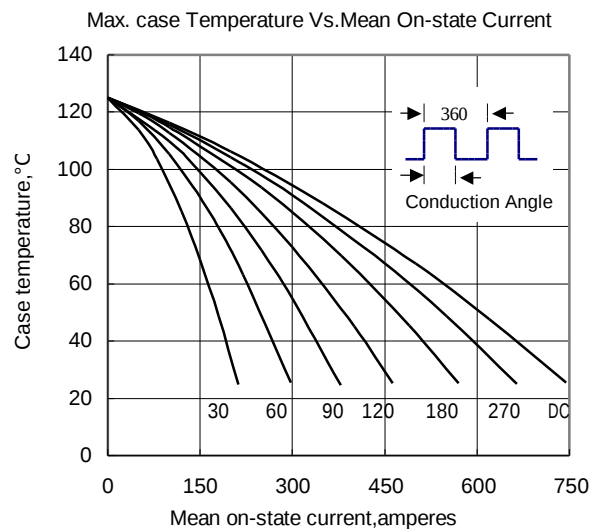


Fig.6

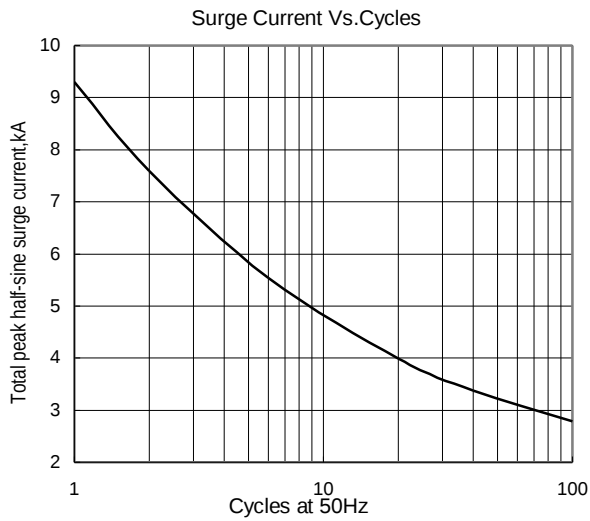


Fig.7

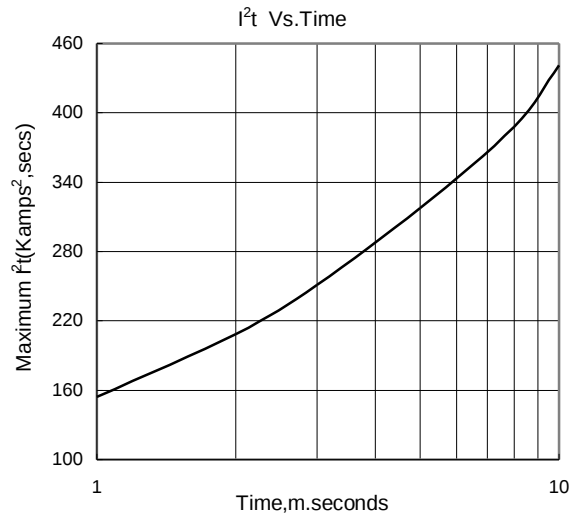


Fig.8

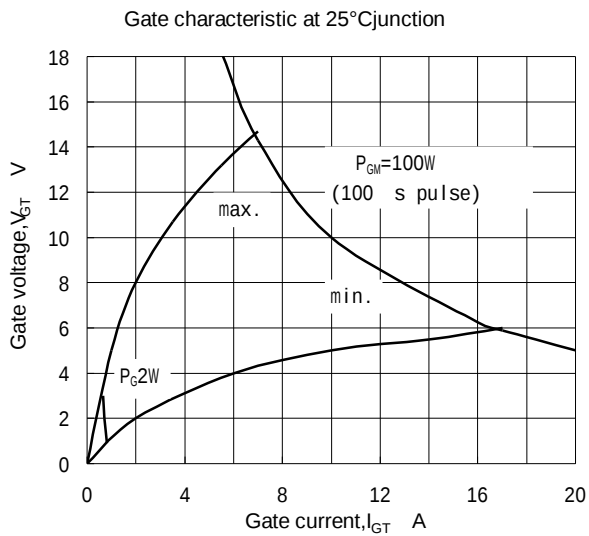


Fig.9

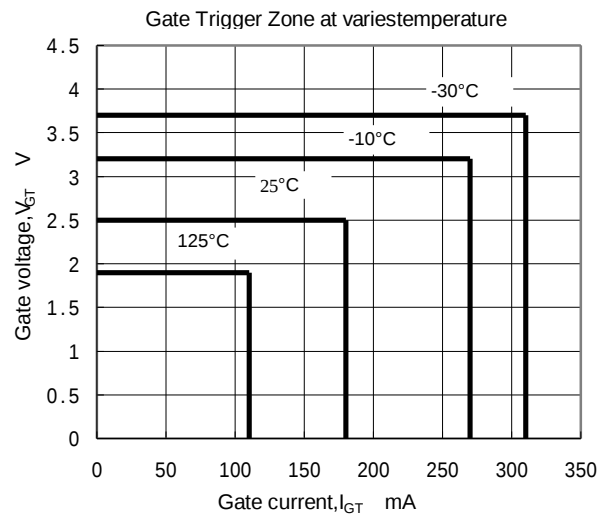


Fig.10